Low-Voltage CMOS 16-Bit Transparent Latch With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX16373 is a high performance, non-inverting 16-bit transparent latch operating from a 2.7 to 3.6V supply. The device is byte controlled. Each byte has separate Output Enable and Latch Enable inputs. These control pins can be tied together for full 16-bit operation. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5V allows MC74LCX16373 inputs to be safely driven from 5V devices.

The MC74LCX16373 contains 16 D-type latches with 3-state 5V-tolerant outputs. When the Latch Enable (LEn) inputs are HIGH, data on the Dn inputs enters the latches. In this condition, the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The <u>3-state</u> outputs are controlled by the Output Enable (OEn) inputs. When OE is LOW, the outputs are enabled. When OE is HIGH, the standard outputs are in the high impedance state, but this does not interfere with new data entering into the latches.

- Designed for 2.7 to 3.6V V_{CC} Operation
- 5.4ns Maximum tpd
- 5V Tolerant Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When VCC = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (20µA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V



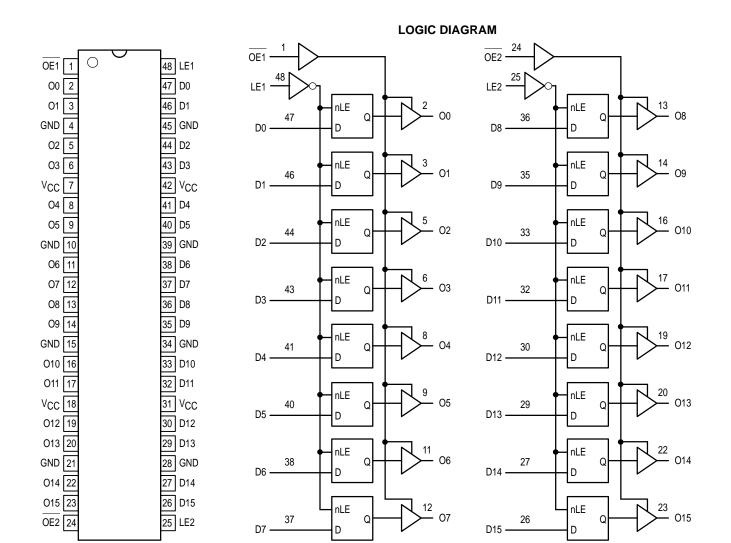
PIN NAMES

Pins	Function
OEn	Output Enable Inputs
LEn	Latch Enable Inputs
D0–D15	Inputs
O0–O15	Outputs



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MC74LCX16373



	Inputs		Outputs	Inputs			Outputs
LE1	OE1	D0:7	O0:7	LE2	OE2	D8:15	O8:15
Х	н	Х	Z	Х	Н	Х	Z
н	L	L	L	Н	L	L	L
Н	L	Н	Н	Н	L	Н	Н
L	L	Х	O0	L	L	Х	O0

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions Are Acceptable, for I_{CC} reasons, DO NOT FLOAT Inputs

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
VCC	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \le V_I \le +7.0$		V
VO	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3–State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1.	V
ΙIK	DC Input Diode Current	-50	V _I < GND	mA
юк	DC Output Diode Current	-50	V _O < GND	mA
		+50	VO > NCC	mA
Ι _Ο	DC Output Source/Sink Current	±50		mA
ICC	DC Supply Current Per Supply Pin	±100		mA
IGND	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.
1. Output in HIGH or LOW State. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit
VCC	Supply Voltage Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage	0		5.5	V
VO	Output Voltage (HIGH or LOW State) (3–State)	0 0		V _{CC} 5.5	V
ЮН	HIGH Level Output Current, $V_{CC} = 3.0V - 3.6V$			-24	mA
IOL	LOW Level Output Current, $V_{CC} = 3.0V - 3.6V$			24	mA
IОН	HIGH Level Output Current, $V_{CC} = 2.7V - 3.0V$			-12	mA
IOL	LOW Level Output Current, $V_{CC} = 2.7V - 3.0V$			12	mA
Т _А	Operating Free–Air Temperature	-40		+85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, V _{IN} from 0.8V to 2.0V, V _{CC} = 3.0V	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = −40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2.)	$2.7V \le V_{CC} \le 3.6V$	2.0		V
VIL	LOW Level Input Voltage (Note 2.)	$2.7 \text{V} \leq \text{V}_{CC} \leq 3.6 \text{V}$		0.8	V
VOH	HIGH Level Output Voltage	$2.7V \leq V_{CC} \leq 3.6V; \ I_{OH} = -100 \mu A$	V _{CC} – 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -12mA$	2.2		
		$V_{CC} = 3.0V; I_{OH} = -18mA$	2.4		
		$V_{CC} = 3.0V; I_{OH} = -24mA$	2.2		
VOL	LOW Level Output Voltage	$2.7V \leq V_{CC} \leq 3.6V; \ I_{OL} = 100 \mu A$		0.2	V
		V _{CC} = 2.7V; I _{OL} = 12mA		0.4	
		V _{CC} = 3.0V; I _{OL} = 16mA		0.4	
		V _{CC} = 3.0V; I _{OL} = 24mA		0.55	

2. These values of V₁ are used to test DC electrical characteristics only.

DC ELECTRICAL CHARACTERISTICS (continued)

			T _A = −40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
Ц	Input Leakage Current	$2.7 \text{V} \leq \text{V}_{CC} \leq 3.6 \text{V}; \ 0 \text{V} \leq \text{V}_{I} \leq 5.5 \text{V}$		±5.0	μΑ
loz	3-State Output Current	$2.7 \leq V_{CC} \leq 3.6 \text{V}; \ 0 \text{V} \leq \text{V}_{O} \leq 5.5 \text{V}; \\ \text{V}_{I} = \text{V}_{IH} \ \text{or} \ \text{V} \ \text{IL}$		±5.0	μΑ
IOFF	Power–Off Leakage Current	$V_{CC} = 0V$; V_I or $V_O = 5.5V$		10	μA
ICC	Quiescent Supply Current	$2.7 \leq V_{CC} \leq 3.6 \textrm{V}; ~\textrm{V}_{\textrm{I}} = \textrm{GND} ~\textrm{or} ~\textrm{V}_{CC}$		20	μA
		$2.7 \leq V_{CC} \leq 3.6 \text{V}; \ 3.6 \leq \text{V}_{I} \text{ or } \text{V}_{O} \leq 5.5 \text{V}$		±20	μΑ
ΔICC	Increase in I _{CC} per Input	$2.7 \leq V_{CC} \leq 3.6 \text{V}; \text{ V}_{IH} = V_{CC} - 0.6 \text{V}$		500	μΑ

AC CHARACTERISTICS ($t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$)

				Lin	nits		
				T _A = -40°	C to +85°C		
			V _{CC} = 3.	0V to 3.6V	V _{CC} :	= 2.7V	1
Symbol	Parameter	Waveform	Min	Max	Min	Max	Unit
^t PLH ^t PHL	Propagation Delay D _n to O _n	1	1.5 1.5	5.4 5.4	1.5 1.5	5.9 5.9	ns
^t PLH ^t PHL	Propagation Delay LE to O _n	3	1.5 1.5	5.5 5.5	1.5 1.5	6.4 6.4	ns
^t PZH ^t PZL	Output Enable Time to HIGH and LOW Level	2	1.5 1.5	6.1 6.1	1.5 1.5	6.5 6.5	ns
^t PHZ ^t PLZ	Output Disable Time from HIGH and LOW Level	2	1.5 1.5	6.0 6.0	1.5 1.5	6.3 6.3	ns
t _s	Setup TIme, HIGH or LOW D _n to LE	3	2.5		2.5		ns
t _h	Hold Time, HIGH or LOW D _n to LE	3	1.5		1.5		ns
tw	LE Pulse Width, HIGH	3	3.0		3.0		ns
^t OSHL ^t OSLH	Output-to-Output Skew (Note 3.)			1.0 1.0			ns

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH–to–LOW (t_{OSHL}) or LOW–to–HIGH (t_{OSLH}); parameter guaranteed by design.

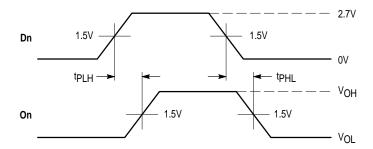
DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
VOLP	Dynamic LOW Peak Voltage (Note 4.)	V_{CC} = 3.3V, C_{L} = 50pF, V_{IH} = 3.3V, V_{IL} = 0V		0.8		V
VOLV	Dynamic LOW Valley Voltage (Note 4.)	V_{CC} = 3.3V, C_{L} = 50pF, V_{IH} = 3.3V, V_{IL} = 0V		0.8		V

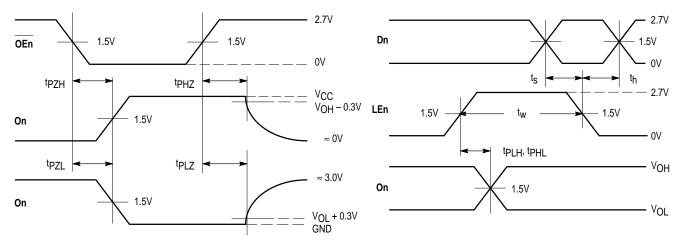
4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

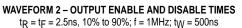
Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 3.3$ V, $V_{I} = 0$ V or V_{CC}	7	pF
COUT	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10MHz, V _{CC} = 3.3V, V _I = 0V or V _{CC}	20	pF



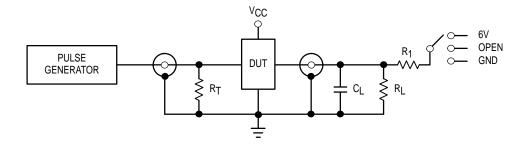
WAVEFORM 1 - PROPAGATION DELAYS tR = tF = 2.5ns, 10% to 90%; f = 1MHz; tW = 500ns



WAVEFORM 3 - LE to On PROPAGATION DELAYS, LE MINIMUM PULSE WIDTH, Dn to LE SETUP AND HOLD TIMES $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1MHz; $t_W = 500$ ns except when noted





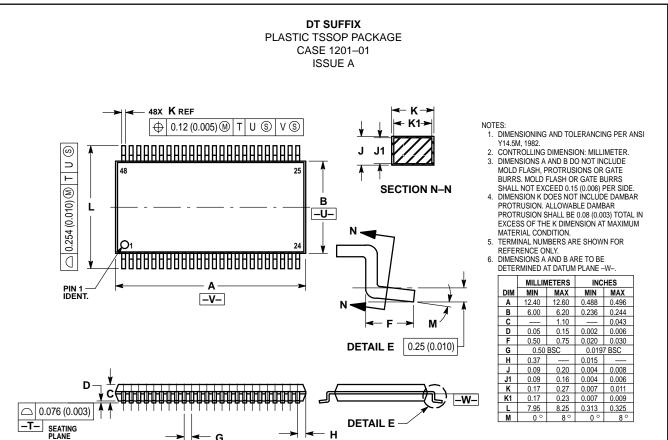


TEST	SWITCH
^t PLH ^{, t} PHL	Open
tPZL, tPLZ	6V
Open Collector/Drain tPLH and tPHL	6V
^t PZH ^{, t} PHZ	GND

 $C_L = 50 pF$ or equivalent (Includes jig and probe capacitance) $R_L = R_1 = 500\Omega$ or equivalent $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 2. Test Circuit

OUTLINE DIMENSIONS



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